

Switchmode Full Plastic Single Ultra-fast Power Rectifiers

Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- $* Low \, T_{RR}$
- *High Surge Capacity
- *Low Power Loss, High efficiency
- *175° Operating Junction Temperature
- *Low Forward Voltage , High Frequency
- *High-Switching Speed 21(typ.) Nanosecond Recovery Time
- *Plastic Material used Carries Underwriters Laboratory



* In compliance with EU RoHs 2002/95/EC directives

MAXIMUM RATINGS

Characteristic		UFF16C 60	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	V
RMS Reverse Voltage	V _{R(RMS)}	420	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R), T_C =125 $^{\circ}$ C	I _{F(AV)}	8 16	А
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz,T _C =125°C)	I _{FM}	8.0	А
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I _{FSM}	150	Α
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +175	$^{\circ}$

THERMAL RESISTANCES

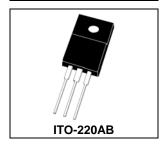
Typical Thermal Resistance junction to case	$R_{\theta jc}$	4.2	°C/w
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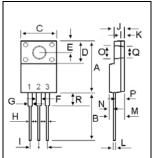
ELECTRICAL CHARACTERISTICS

22291110/12 011/11/10121100					
Characteristic	Symbol	Min	Туре	Max.	Unit
Maximum Instantaneous Forward Voltage (per diode) (I_F =8 Amp T_C = 25 $^{\circ}$ C)	V _F		1.85	2.2	٧
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R		 	25 500	uA uA
Reverse Recovery Time ($I_F = 0.5 \text{ A}$, $I_R = 1.0$, $I_{rr} = 0.25 \text{ A}$)	T _{rr}		20	25	ns

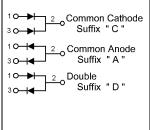
ULTRA FAST RECTIFIERS

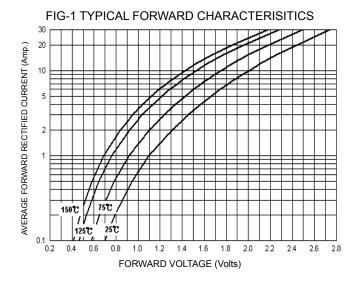
16 AMPERES 600 VOLTS

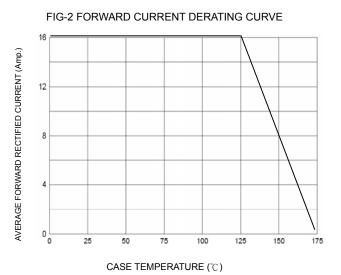


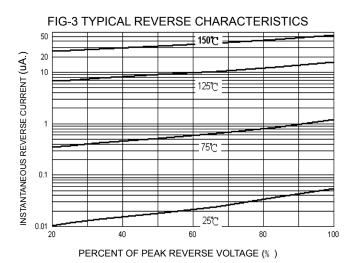


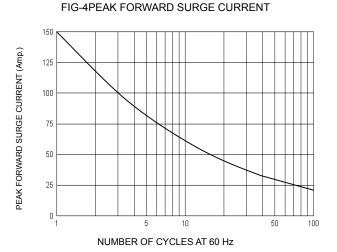
DIM	MILLIMETERS		
וווט	MIN	MAX	
Α	15.05	15.15	
В	13.35	13.45	
С	10.00	10.10	
D	6.55	6.65	
E	2.65	2.75	
F	1.55	1.65	
G	1.20	1.47	
Н	0.55	0.65	
- 1	2.50	2.60	
J	3.00	3.20	
K	1.10	1.20	
L	0.55	0.65	
M	4.40	4.60	
N	1.15	1.25	
0	3.35	3.45	
Р	2.65	2.75	
Q	3.15	3.25	
R	3.60	3.80	

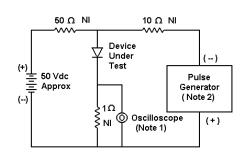


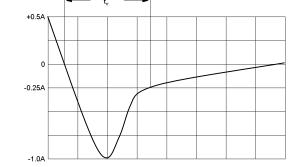












- 1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

Set time base for 10/20 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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